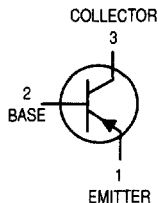


General Purpose Transistors

PNP Silicon



MPS2907 MPS2907A*

*Motorola Preferred Device



CASE 29-04, STYLE 1
TO-92 (TO-226AA)

MAXIMUM RATINGS

Rating	Symbol	MPS2907	MPS2907A	Unit
Collector-Emitter Voltage	V_{CEO}	-40	-60	Vdc
Collector-Base Voltage	V_{CBO}	-60		Vdc
Emitter-Base Voltage	V_{EBO}	-5.0		Vdc
Collector Current — Continuous	I_C	-600		mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	625	5.0	mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.5	12	Watts mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-500 to +150		$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	$^\circ\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage ⁽¹⁾ ($I_C = -10$ mAdc, $I_B = 0$)	MPS2907 MPS2907A	$V_{(BR)CEO}$	-40 -60	— —	Vdc
Collector-Base Breakdown Voltage ($I_C = -10$ μ Adc, $I_E = 0$)		$V_{(BR)CBO}$	-60	—	Vdc
Emitter-Base Breakdown Voltage ($I_E = -10$ μ Adc, $I_C = 0$)		$V_{(BR)EBO}$	-5.0	—	Vdc
Collector Cutoff Current ($V_{CE} = -30$ Vdc, $V_{EB(off)} = -0.5$ Vdc)		I_{CEX}	—	-50	nAdc
Collector Cutoff Current ($V_{CB} = -50$ Vdc, $I_E = 0$)	MPS2907 MPS2907A	I_{CBO}	— —	-0.02 -0.01	μ Adc
($V_{CB} = -50$ Vdc, $I_E = 0$, $T_A = 150^\circ\text{C}$)	MPS2907 MPS2907A		— —	-20 -10	
Base Current ($V_{CE} = -30$ Vdc, $V_{EB(off)} = -0.5$ Vdc)		I_B	—	-50	nAdc

1. Pulse Test: Pulse Width ≤ 300 μ s, Duty Cycle $\leq 2.0\%$.

Preferred devices are Motorola recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS				
DC Current Gain ($I_C = -0.1$ mA dc, $V_{CE} = -10$ V dc)	h_{FE}	MPS2907	35	—
		MPS2907A	75	—
($I_C = -1.0$ mA dc, $V_{CE} = -10$ V dc)		MPS2907	50	—
		MPS2907A	100	—
($I_C = -10$ mA dc, $V_{CE} = -10$ V dc)		MPS2907	75	—
	MPS2907A	100	—	
($I_C = -150$ mA dc, $V_{CE} = -10$ V dc) ⁽¹⁾	MPS2907, MPS2907A	100	300	
($I_C = -500$ mA dc, $V_{CE} = -10$ V dc) ⁽¹⁾	MPS2907	30	—	
	MPS2907A	50	—	
Collector-Emitter Saturation Voltage ⁽¹⁾ ($I_C = -150$ mA dc, $I_B = -15$ mA dc)	$V_{CE(sat)}$	—	-0.4	V dc
($I_C = -500$ mA dc, $I_B = -50$ mA dc)		—	-1.6	
Base-Emitter Saturation Voltage ⁽¹⁾ ($I_C = -150$ mA dc, $I_B = -15$ mA dc)	$V_{BE(sat)}$	—	-1.3	V dc
($I_C = -500$ mA dc, $I_B = -50$ mA dc)		—	-2.6	

SMALL-SIGNAL CHARACTERISTICS

Current-Gain — Bandwidth Product ^{(1), (2)} ($I_C = -50$ mA dc, $V_{CE} = -20$ V dc, $f = 100$ MHz)	f_T	200	—	MHz
Output Capacitance ($V_{CB} = -10$ V dc, $I_E = 0$, $f = 1.0$ MHz)	C_{obo}	—	8.0	pF
Input Capacitance ($V_{EB} = -2.0$ V dc, $I_C = 0$, $f = 1.0$ MHz)	C_{ibo}	—	30	pF

SWITCHING CHARACTERISTICS

Turn-On Time	$(V_{CC} = -30$ V dc, $I_C = -150$ mA dc, $I_{B1} = -15$ mA dc) (Figures 1 and 5)	t_{on}	—	45	ns
Delay Time		t_d	—	10	ns
Rise Time		t_r	—	40	ns
Turn-Off Time	$(V_{CC} = -6.0$ V dc, $I_C = -150$ mA dc, $I_{B1} = I_{B2} = 15$ mA dc) (Figure 2)	t_{off}	—	100	ns
Storage Time		t_s	—	80	ns
Fall Time		t_f	—	30	ns

1. Pulse Test: Pulse Width ≤ 300 μs , Duty Cycle $\leq 2.0\%$.
2. f_T is defined as the frequency at which $|h_{fe}|$ extrapolates to unity.

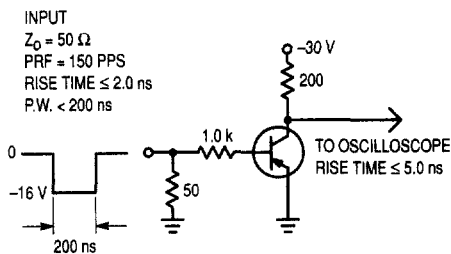


Figure 1. Delay and Rise Time Test Circuit

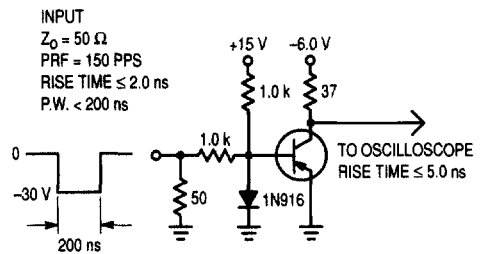


Figure 2. Storage and Fall Time Test Circuit

TYPICAL CHARACTERISTICS

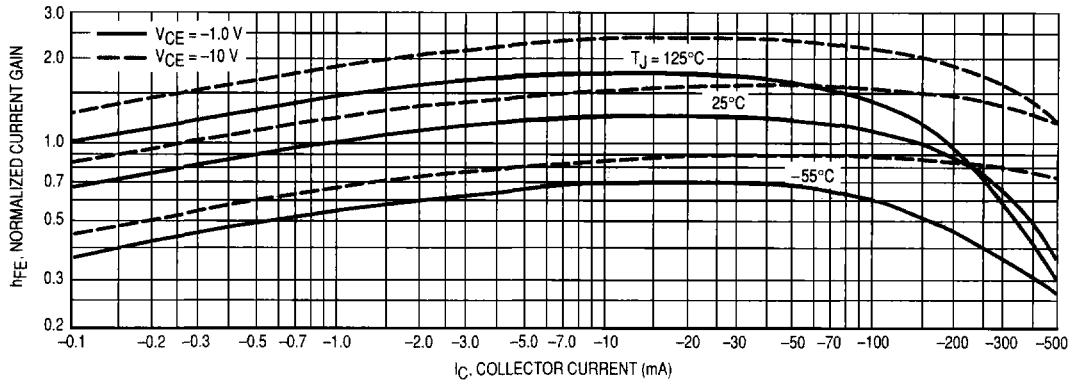


Figure 3. DC Current Gain

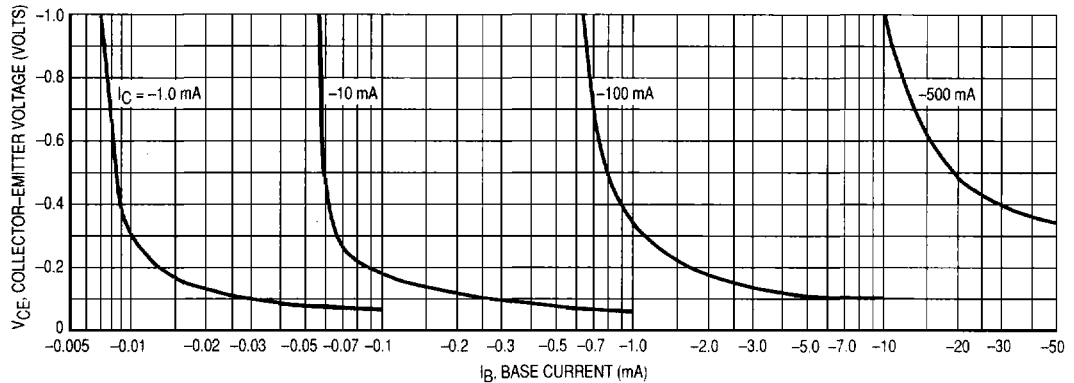


Figure 4. Collector Saturation Region

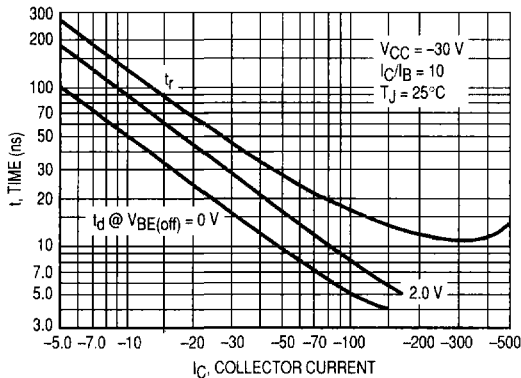


Figure 5. Turn-On Time

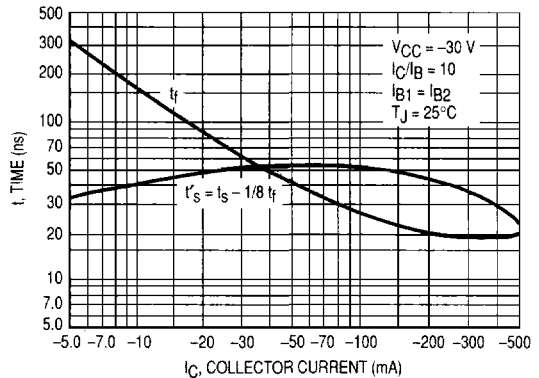


Figure 6. Turn-Off Time

TYPICAL SMALL-SIGNAL CHARACTERISTICS
NOISE FIGURE
VCE = 10 Vdc, TA = 25°C

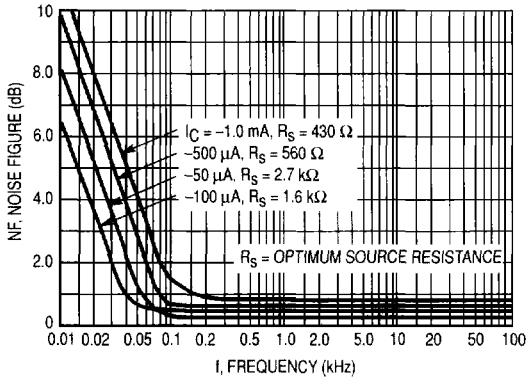


Figure 7. Frequency Effects

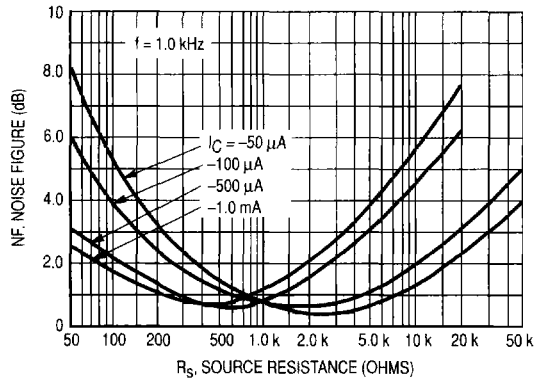


Figure 8. Source Resistance Effects

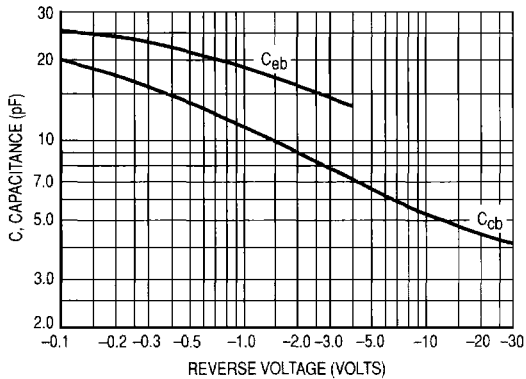


Figure 9. Capacitances

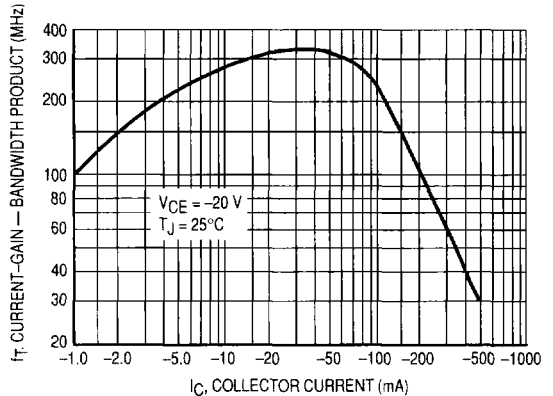


Figure 10. Current-Gain — Bandwidth Product

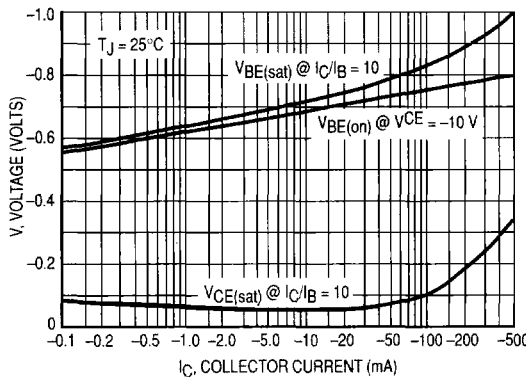


Figure 11. "On" Voltage

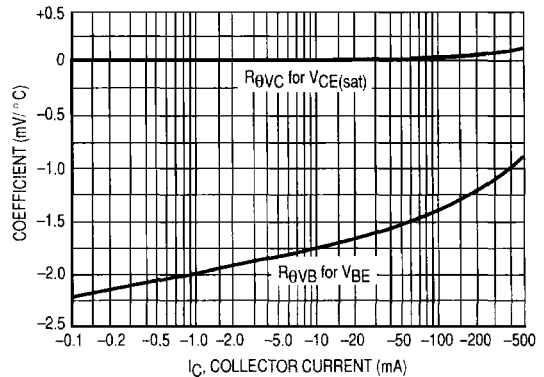


Figure 12. Temperature Coefficients